Thyristor Semiconductor Device - Page 1 of 1



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#### Inclosure Material:

Metal

**Overall Length:** 

1.646 inches

# Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-48

#### **Mounting Method:**

Threaded stud

## **Overall Width Across Flats:**

Between 0.544 inches and 0.562 inches

#### Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

2.0 forward voltage, peak and 3.0 gate trigger voltage, dc and 720.0 reverse voltage, peak

## **Current Rating Per Characteristic:**

80.00 milliamperes forward current, total rms preset

## **Special Features:**

Junction pattern arrangement: pnpn

## **Thread Series Designator:**

Unf

## **Terminal Type And Quantity:**

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

## Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0